NSN 5962-01-264-0758

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View Online at https://aerobasegroup.com/nsn/5962-01-264-0758 **Body Length:** 0.460 inches **Body Width:** 0.460 inches **Body Height:** 0.100 inches **Maximum Power Dissipation Rating:** 1.04 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and monolithic and positive outputs **Inclosure Material:** Ceramic **Inclosure Configuration:** Leadless flat pack **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 14 input **Case Outline Source And Designator:** C-4 mil-m-38510 **Current Rating Per Characteristic:** 190.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -0.3 volts power source and 7.0 volts power source **Capitance Rating Per Characteristic:** 10.00 input picofarads and 13.00 output picofarads **Time Rating Per Chacteristic:** 100.00 nanoseconds delay **Memory Device Type:** Prom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 28 leadless Shelf Life:

N/a

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Demilitarization:

Yes - demil/mli

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